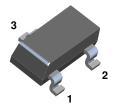


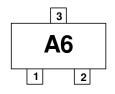
EN: This Datasheet is presented by the manufacturer.

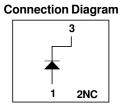
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BAS16







SOT-23

Small Signal Diode

Absolute Maximum Ratings*

T_A = 25 °C unless otherwise noted

Symbol	Parameter	Value	Units
V_{RRM}	Maximum Repetitive Reverse Voltage	85	V
I _{F(AV)}	Average Rectified Forward Current	200	mA
I _{FSM}	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 second Pulse Width = 1.0 microsecond	1.0 2.0	A A
T _{stg}	Storage Temperature Range	-55 to +150	°C
T _J	Operating Junction Temperature	-55 to +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics

Symbol	Parameter	Value	Units
P_{D}	Power Dissipation	350	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

Electrical Characteristics T_A = 25 °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
V _R	Breakdown Voltage	I _R = 5.0 μA	85		V
V _F	Forward Voltage	$I_F = 1.0 \text{ mA}$ $I_F = 10 \text{ mA}$ $I_F = 50 \text{ mA}$ $I_F = 150 \text{ mA}$		715 855 1.0 1.25	mV mV V
I _R	Reverse Current	V _R = 75 V V _R = 25 V, T _A = 150°C V _R = 75 V, T _A = 150°C		1.0 30 50	μΑ μΑ μΑ
C _T	Total Capacitance	$V_R = 0, f = 1.0 \text{ MHz}$		2.0	pF
t _{rr}	Reverse Recovery Time	$I_F = I_R = 10 \text{ mA}, I_{RR} = 1.0 \text{ mA},$ $R_L = 100 \Omega$		6.0	ns

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Small Signal Diode

(continued)

Typical Characteristics

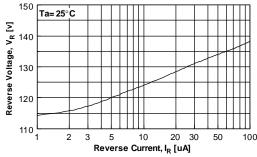


Figure 1. Reverse Voltage vs Reverse Current BV - 1.0 to 100 uA

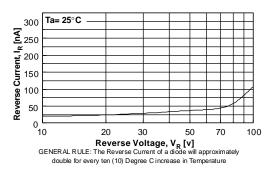


Figure 2. Reverse Current vs Reverse Voltage IR - 10 to 100 V

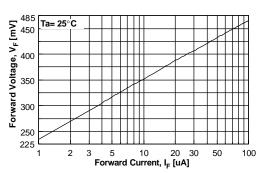


Figure 3. Forward Voltage vs Forward Current VF - 1.0 to 100 uA

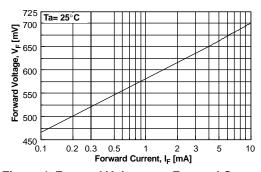


Figure 4. Forward Voltage vs Forward Current VF - 0.1 to 10 mA

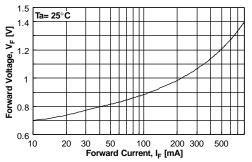


Figure 5. Forward Voltage vs Forward Current VF - 10 - 800 mA

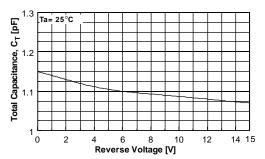


Figure 6. Total Capacitance

Small Signal Diode

(continued)

Typical Characteristics (continued)

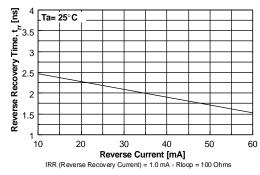


Figure 7. Reverse Recovery Time vs Reverse Current TRR - IR 10 mA vs 60 mA

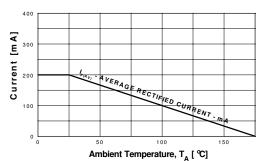
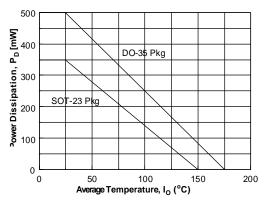


Figure 8. Average Rectified Current (IF(AV))
versus Ambient Temperature (TA)



Figrue 9. Power Derating Curve

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